Product Preview

Hybrid Power Module

Integrated Power Stage for 2.0 hp 460 VAC Motor Drive

This module integrates a 3-phase inverter, 3-phase rectifier, brake, and temperature sense in a single convenient package. It is designed for 2.0 hp general purpose 3-phase induction motor drive applications. The inverter incorporates advanced insulated gate bipolar transistors (IGBT) matched with fast soft free-wheeling diodes to give optimum performance. The solderable top connector pins are designed for easy interfacing to the user's control board.

- Short Circuit Rated 10 μs @ 125°C, 720 V
- Pin-to-Baseplate Isolation Exceeds 2500 Vac (rms)
- Compact Package Outline
- · Access to Positive and Negative DC Bus
- Independent Brake Circuit Connections
- · UL Recognition Pending

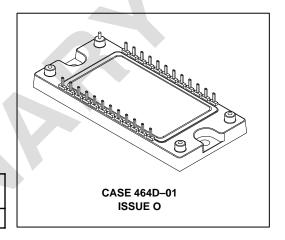
ORDERING INFORMATION

Device	Voltage	Current	Equivalent		
	Rating	Rating	Horsepower		
PHPM7A10S120DC3	1200	10	2.0		

MHPM7A10S120DC3

Motorola Preferred Device

10 AMP, 1200 VOLT HYBRID POWER MODULE



MAXIMUM DEVICE RATINGS (T, J = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit	
Repetitive Peak Input Rectifier Reverse Voltage (T _J = 25°C to 150°C)	V _{RRM}	900	V	
Non–Repetitive Peak Input Rectifier Reverse Voltage (1) (T _J = 25°C to 150°C)	VRSM	1600	V	
IGBT Reverse Voltage	V _{CES}	1200	V	
Gate-Emitter Voltage	V _{GES}	±20	V	
Continuous IGBT Collector Current (T _C = 25°C)	I _{Cmax}	10	А	
Repetitive Peak IGBT Collector Current (2)	I _{C(pk)}	20	А	
Continuous Free–Wheeling Diode Current (T _C = 25°C)	IFmax	10	А	
Continuous Free–Wheeling Diode Current (T _C = 80°C)	I _{F80}	8.6	А	
Repetitive Peak Free–Wheeling Diode Current (2)	I _{F(pk)}	20	А	
Average Converter Output Current (Peak-to-Average ratio of 10, T _C = 95°C)	I _{Omax}	16	А	
IGBT Power Dissipation per die (T _C = 95°C)	PD	29	W	
Free–Wheeling Diode Power Dissipation per die (T _C = 95°C)	PD	13	W	
Junction Temperature Range	TJ	-40 to +150	°C	
Short Circuit Duration (V _{CE} = 720 V, T _J = 125°C)	t _{sc}	10	μs	
Isolation Voltage, pin to baseplate	V _{ISO}	2500	Vac	
Operating Case Temperature Range	T _C	-40 to +95	°C	
Storage Temperature Range	T _{stg}	-40 to +150	°C	
Mounting Torque — Heat Sink Mounting Holes	_	12	lb-in	

⁽¹⁾ Half-Sine 60 Hz, maximum reverse voltage capability decreases by 0.1% per °C at lower temperature

Preferred devices are Motorola recommended choices for future use and best overall value.

This document contains information on a product under development. Motorola reserves the right to change or discontinue this product without notice.



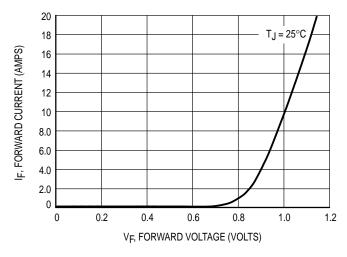
⁽²⁾ 1.0 ms = 1.0% duty cycle

MHPM7A10S120DC3

ELECTRICAL CHARACTERISTICS ($T_J = 25^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
DC AND SMALL SIGNAL CHARACTERISTICS					
Input Rectifier Forward Voltage (IF = 10 A)	٧F	_	1.02	1.25	V
Gate–Emitter Leakage Current (V _{CE} = 0 V, V _{GE} = ±20 V)	IGES	_	_	±20	μΑ
Collector–Emitter Leakage Current (V _{CE} = 1200 V, V _{GE} = 0 V)	ICES	_	5.0	100	μΑ
Gate-Emitter Threshold Voltage (V _{CE} = V _{GE} , I _C = 1.0 mA)	V _{GE(th)}	4.0	6.0	8.0	V
Collector–Emitter Breakdown Voltage (I _C = 10 mA, V _{GE} = 0 V)	V _(BR) CES	1200	_	_	V
Collector–Emitter Saturation Voltage (I _C = I _{Cmax} , V _{GE} = 15 V)	V _{CE(sat)}	_	2.5	3.5	V
Free–Wheeling Diode Forward Voltage (I _F = I _{Fmax} , V _{GE} = 0 V)	٧ _F	1.8	2.0	2.4	V
Input Capacitance (VGE = 0 V, VCE = 25 V, f = 1.0 MHz)	C _{ies}	_<	1200	_	pF
Input Gate Charge (V _{CE} = 600 V, I _C = I _{Cmax} , V _{GE} = 15 V)	QT		65	_	nC
THERMAL CHARACTERISTICS, EACH DIE					
Thermal Resistance — IGBT	$R_{ heta}$ JC	-	1.4	1.9	°C/W
Thermal Resistance — Free–Wheeling (Fast Soft) Diode	$R_{ heta}$ JC		3.2	4.2	°C/W
Thermal Resistance — Input Rectifier	$R_{ heta}$ JC	> -	3.2	4.2	°C/W
TEMPERATURE SENSE DIODE					
Forward Voltage (@ I _F = 1.0 mA)	VF	1.983	2.024	2.066	V
Forward Voltage Temperature Coefficient (@ I _F = 1.0 mA)	TC _{VF}	_	-8.64	_	mV/°C

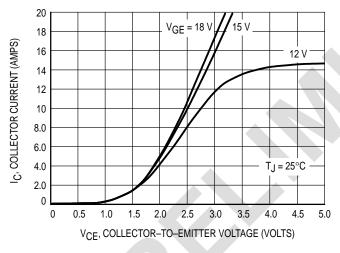
TYPICAL CHARACTERISTICS



20 $T_J = 125$ °C 18 IF, FORWARD CURRENT (AMPS) 16 14 12 25°C 10 8.0 6.0 4.0 2.0 0.5 1.0 1.5 2.0 2.5 VF, FORWARD VOLTAGE (VOLTS)

Figure 1. Forward Characteristics — Input Rectifier

Figure 2. Forward Characteristics — Free–Wheeling Diode



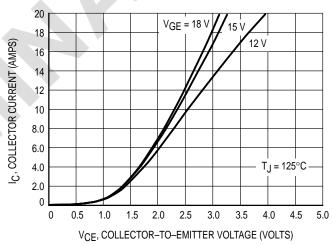


Figure 3. Forward Characteristics, T_J = 25°C

Figure 4. Forward Characteristics, T_J = 125°C

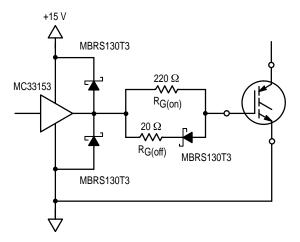
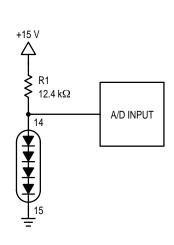


Figure 5. Recommended Gate Drive Circuit

TYPICAL CHARACTERISTICS



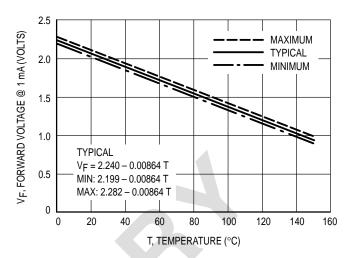


Figure 6. Recommended Temperature Sense Bias Circuit

Figure 7. BAV99LT1 Temperature Sense Diode Performance: V_F = 2.59 – 7.31E–3 T_C

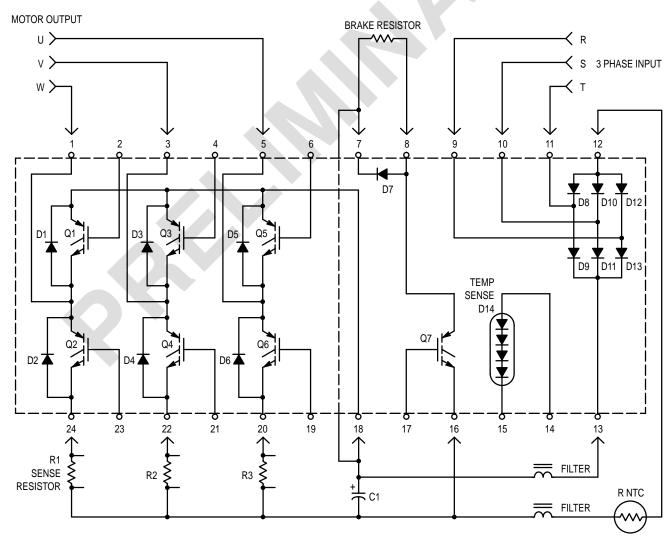
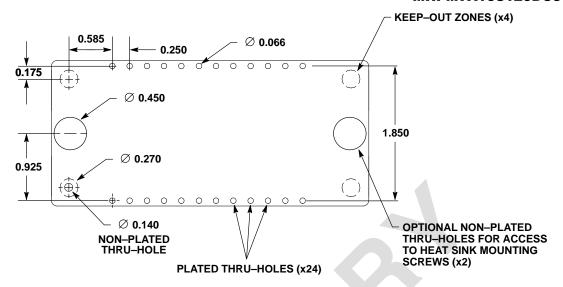


Figure 8. Schematic of Module, Showing Pin–Out and External Connections

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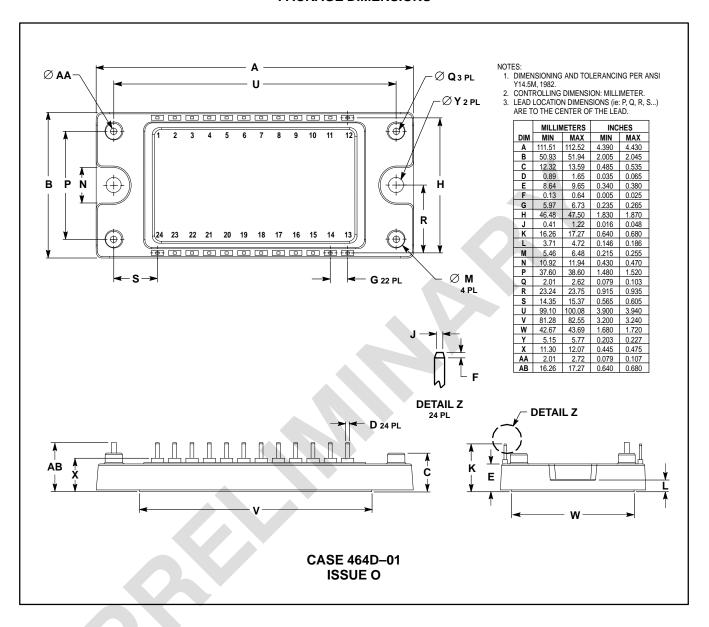


NOTES:

- Package is symmetrical, except for a polarizing plastic post near pin 1, indicated by a non-plated thru-hole in the footprint.
- 2. Dimension of plated thru-holes indicates finished hole size after plating.
- 3. Access holes for mounting screws may or may not be necessary depending on assembly plan for finished product.

Figure 9. Package Footprint (Dimensions in Inches)

PACKAGE DIMENSIONS



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